eAMS Series

16 Bits DSP Sound Processor

Product Specification

Doc. Version 1.7

ELAN MICROELECTRONICS CORP.

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Specification Revision History

Doc. Version	Revision Description	Date
1.0	 Added eAM096S, eAM192S and eAM384S Modified the Operating temperature range in Section 7.2 	2006/10/31
1.1	 Modified the Application Circuits in Section 7 Modified the Boot SPI in Section 5 Modified the Application Circuits in Section 8 Modified the Sampleing Rate Range in Section 4 Added the IOVDD, IOVSS, AVDD, AVSS in Section 6.1 	2007/04/12
1.2	Modified the Temperature Range in Section 7.2	2007/08/10
1.3	 Added package information in Section 4 Modifed Application Circuit in Section 8 	2007/11/10
1.4	Modified PWM current in Section 6.3	2008/01/10
1.5	Modified Application Circuit in Section 8	2008/10/15
1.6	Modified Algorithm-related information in Section 5	2009/04/15
1.7	1. Modified Application Circuit in Section 9	2009/12/1



1 General Description

The ELAN eAMS Series IC is a 16-bit DSP Sound Processor with multi-channel speech and instrument playback. It is based on ELAN 16-bit DSP platform. The series has a powerful 16-bit DSP architecture that handles most of the speech / melody functions. Speech and melody can be played back simultaneously. The speech synthesis is implemented by software and supports a wide range of compression bit rates and various volume levels. The ELAN eAMS Series provides real instrument waveform to obtain good quality melody. The ELAN eAMS peripheral includes RTC, Timer, WDT, DAC, PWM, etc.

The ELAN eAMS Series IC's offer Fast mode, Sleep mode, Green mode, and Slow mode of operation. The use of Green/Slow mode will further reduce the power consumption. Green mode also provides RTC function for wake-up purposes.

The ELAN eAMS Series enhanced features make it suitable for versatile voice and sound effect product applications. These enhanced versatile features allow users to create products with a wide variety of new fancy ideas.

The ELAN eAMS Series have extreme high performance in melody application based on powerful DSP architecture and good algorithm in audio compression.

2 Features

MCU

- 16-bit RISC CPU architecture
- CPU clock: 20 MHz @ 3.3V
- · Programmable PLL
- · Four CPU operation modes: fast, slow, green, sleep
- Powerful DSP Instruction Set supports multiplication, division, repeat, loop and soft interrupt instructions
- Saturation mode is supported for multimedia applications
- Eight general purpose registers (GPR)
- 18 interrupt sources with 2-level priority

Memory

- 32K-word program memory
- · 2K-word data RAM
- 096/128/192/256/384/512K-word data ROM

Peripherals

- Real Time Clock (RTC) with wake-up function
- Four 8-bit timers, two general purpose timers, two multiple-function timers
- 8-bit Watchdog Timer (WDT) with general purpose timer capability
- 24 GPIO



3 Block Diagram

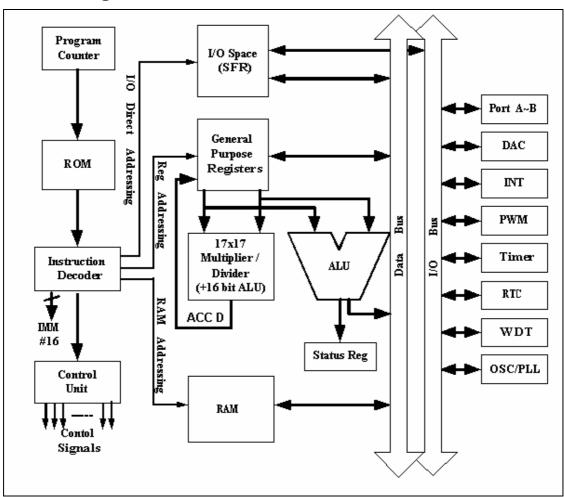


Figure 3-1 ELAN eAMS System Block Diagram



4 Selection Table

The ELAN eAMS Series integrates an extensive range of features, most of which are common to all devices, except for some distinctive features like Data ROM and Coding Type. For user convenience in the choice of the most suitable product for their application, the following table is provided, which enumerates the main features of each device.

Product No.	eAM096S	eAM128S	eAM192S	eAM256S	eAM384S	eAM512S		
Pin Count	45							
Program ROM		32K × 16						
Data RAM	2K ×16							
Data ROM	96K×16	128K×16	192K×16	256K×16	384K×16	512K×16		
Timer			4 × 8-b	it timers				
Watchdog	Yes							
PWM	10-bit							
Current D/A	12-bit							
1/0			24 I/C	ports				



5 Algorithm Selection Table

The ELAN eAMS Series algorithm feature:

- 12-bit current-steering Digital to Analog Converter (DAC)
- 10-bit resolution Pulse Width Modulation (PWM)
- Multiple flash with volume level option
- Directly controls port output value by waveform (waveform control port)
- Supports mark number in waveform with ROM optimized configuration
- Up to 16-channel melody or 12-channel melody + 4-channel speech

Product No.	eAM096S	eAM128S	eAM192S	eAM256S	eAM384S	eAM512S				
Audio*	Up to 16	Up to 16-channel melody or 12-channel melody + 4-channel speech								
	4-bit ADPCM									
Coding Type*	5-bit ADPCM									
	PCM (96K bps @ 8KHz)									
Sampling Rate Range*	6kHz ~ 48KHz									

^{*} For more detailed information, refer to the Assembler Reference Manual and C Macro Reference Manual.



eAMS and eAM Series Comparison

Product No.	eSLZ000	eAM	eAMS
JTAG ICE	Yes	No	No
Boot SPI Yes		No	No
Total I/O Number	48 I/O	48 I/O	24 I/0 (Port A + Port B 0~7)
Large Current I/O Number	8+4	8+4	4 (Port A 12~15)
Wake-up Pin	16+5	16+5	8+4
SPI	Yes	Yes	No
MIC Front-end AGC	Yes	Yes	No
ADC	Yes	Yes	No



Pin Description

7.1 Power Supply

Name	Туре	Supply Voltage	Description	
VDD_CPU	Р	3V	Positive power supply for CPU, digital peripheral and DRAM	
VDD_PM	Р	3V	Positive power supply for PROM, DROM and POR	
VDD_OSC	Р	3V	Positive power supply for Oscillator system and PLL	
IOVDD_PWM	Р	3V, 5V	Positive power supply for PWM I/O pad	
IOVDD_PB	Р	3V, 5V	Positive power supply for Port A.2~15 and Port B I/O pad	
IOVDD*	Р	3V, 5V	Positive power supply	
VSS_CPU	Р	GND	Negative power supply for CPU, digital peripheral and DRAM	
VSS_PM	Р	GND	Negative power supply for PROM, DROM and POR	
VSS_OSC	Р	GND	Negative power supply for Oscillator system and PLL	
IOVSS_PWM	Р	GND	Negative power supply for PWM I/O pad	
IOVSS_PB	Р	GND	Negative power supply for Port A.2~15 and Port B I/O pad	
IOVSS*	Р	GND	Negative power supply	
AVDD_DA	Р	3V	Positive power supply for D/A	
AVDD**	Р	3V	Positive power supply	
AVSS_DA	Р	GND	Negative power supply for D/A	
AVSS**	Р	GND	Negative power supply	
RVIN	Р	5V	Regulator voltage input	
RVOUT	Р	3V	Regulator voltage output 3.0V	

^{*} These power pins must connect to the same VDD and VSS as IOVDD_PB and IOVSS_PB

^{**} These power pins must connect to the same VDD and VSS as AVDD_DA and AVSS_DA



7.2 System Control

Name	Туре	Description
RSTB	1	RSTB is the low active global reset input *
TEST	I	Test mode select pin (High active). Internal pull down. For chip internal test only, Normally connect to VSS.
OSCI	I	Crystal or RC oscillator connecting pin RC or Crystal selection is by OSCS pin
osco	0	Crystal oscillator connecting pin
oscs	I	RC or Crystal selection: 0 = RC 1 = Crystal
PLLC	I	PLL loop filter capacitor **

This pin has an internal pull-up 150K Ω resistor. Refer to the Application Circuit.

7.3 DAC Output

Name	Туре	Description
DACO	0	Current D/A output pin

^{**} This pin must connect a 47nF capacitor to ground. Refer to the Application Circuit.



7.4 I/O Port

Port A Attributes and Definitions

Name	Function	Туре	Description
DAIOI	GPIO	I/O	General-purpose I/O function
PA[0]	PWM0	0	PWM Output 0
DAIAI	GPIO	I/O	General-purpose I/O function
PA[1]	PWM1	0	PWM Output 1
PA[2]	GPIO	I/O	General-purpose I/O function
PA[3]	GPIO	I/O	General-purpose I/O function
DAIAI	GPIO	I/O	General-purpose I/O function
PA[4] PA[5]	TEX12	I	External Timer 2 clock input
DAIEI	GPIO	I/O	General-purpose I/O function
PA[5]	TEX13	I	External Timer 3 clock input
PA [6]	GPIO I/O		General-purpose I/O function
PA [7]	GPIO	I/O	General-purpose I/O function
PA [8]	GPIO	I/O	General-purpose I/O function
PA [0]	TCCP2	I/O	Timer 2 capture input or compare output
PA [9]	GPIO	I/O	General-purpose I/O function
FA [9]	TCCP3	I/O	Timer 3 capture input or compare output
PA [10]	GPIO	I/O	General-purpose I/O function
FA [10]	EXINT0	I	External Interrupt 0 input
PA [11]	GPIO	I/O	General-purpose I/O function
1 7 [11]	EXINT1	I	External Interrupt 1 input
PA [12]	GPIO	I/O	General-purpose I/O function with programmable high current
PA [13]	GPIO	I/O	General-purpose I/O function with programmable high current
PA [14]	GPIO	I/O	General-purpose I/O function with programmable high current
PA [15]	GPIO	I/O	General-purpose I/O function with programmable high current

• Port B Attributes and Definitions

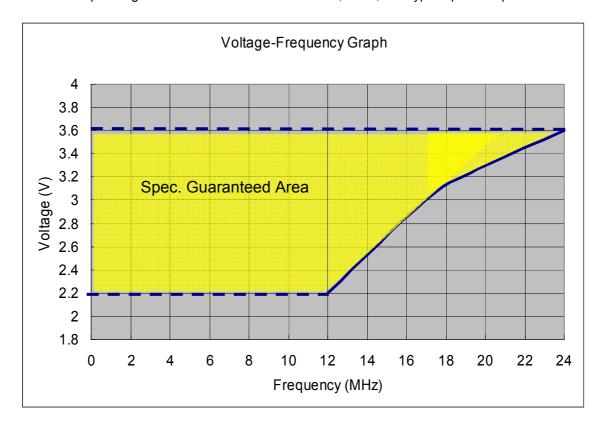
Name	Function	Туре	Description
		I/O	General-purpose I/O function
PB [7:0]	GPIO	I	Wake-up function with programmable pull-up resistor



8 Electrical Characteristics

8.1 CPU Voltage - Frequency Graph

The speed of a MOS device depends on voltage, temperature, and process variation. Performance analysis is based on a combination of these three factors. The central operating condition is characterized at 3.3V, 25°C, and typical process parameters.





8.2 Absolute Maximum Ratings

Parameter	Pins	Symbol	Condition	Rated Value	Unit
Power supply voltage	VDD	V_{DD}	T _A =25°C	-0.3 to +6.0	V
Input voltage	All Input	V _{IN}	T _A =25°C	-0.3 to VDD+0.3	V
Operating temperature range	_	T _A	_	-40 to +85	°C
Storage temperature range	_	T _{STR}	_	-65 to +150	

8.3 DC Characteristics

Standard operation conditions: VDD = 3V, GND=0V, TA = 25°C

Parameter	Pins	Symbol Condition	Rate	ed Value	е	Unit	
Parameter	FIIIS		Condition	Min.	Тур.	Max.	Unit
Power supply voltage	VDD ¹	V	2 batteries	2.2	3.0	3.6	
Power supply voltage	VDD	V _{DD}	3 batteries	3.6	4.5	5.5	
Input voltage	_	V _{IN1}		VDD×0.7	-	VDD	V
	_	V _{IN2}		0	-	VDD×0.3	V
Input threshold voltage	_	_		0.5×VDD	-	0.75×VDD	
(Schmitt Trigger)	_	_		0.2×VDD	_	0.4×VDD	
Pull up resistor	/RESE T	V _{PU1L}	Vin=GND	500	1000	1500	
Pull-up resistor	/RESE T	V _{PU1H}	Vin=2V	80	100	120	kΩ
Pull-down resistor	TEST	R _{PD}	Vin=1V	80	100	120	

¹ Refer to the User Manual Voltage Regulator section for details.



Parameter	Pins	Symbol	Condition	Rated Value			
				Min.	Тур.	Max.	Unit
Ports A, B output high current	IOH0	I _{OH0}	VDD=3V VOH=2.4V	-2	-3	-	mA
Ports A, B output low current	IOL0	I _{OL0}	VDD=3V VOL=0.4V	2	3	l	
Port A [12:15] high current (HD enabled)	IOH2	I _{OH2}	VDD=3V VOH=2.4V	TBD	TBD	l	
Port A [12:15] low current (HD enabled)	IOL2	I _{OL2}	VDD=3V VOL=0.4V	TBD	TBD		
PWM output high current	PWM0 PWM1	I _{PWMH}	VDD=3V VOH=VDD/2 Max. volume	-140	-150	_	
PWM output low current	PWM0 PWM1	I _{PWML}	VDD=3V VOL=VDD/2 Max volume	140	150	_	
DAC output current	DACO	I _{DAC}	VDD=2.2~3.3V	2.5	3	_	
Regulator output high current	RVOUT	I _{OUTH}	RVIN = 4.5V RVOUT = 3.0V Fast, Slow mode	70	_	_	
Regulator output low current	RVOUT	I _{OUTL}	RVIN = 4.5V RVOUT = 3.0V Green, Sleep mode	7	_	_	
Fast mode current consumption increment per MHz	_	I _{FAST}	VDD=3V No load DAC off	_	700	800	- μΑ
Slow mode current consumption	_	I _{SLOW}	VDD=3V No load DAC off	-	70	80	
Green mode current consumption	_	I _{GREEN}	VDD=3V	_	8	10	
Sleep mode current consumption	_	I _{SLEEP}	VDD=3V Regulator on		2	_	
			VDD = 3V Regulator off	_	1	1.2	
CPU operation frequency	_	F _{sys}	VDD = 3V	14	16	_	MHz



9 Application Circuits

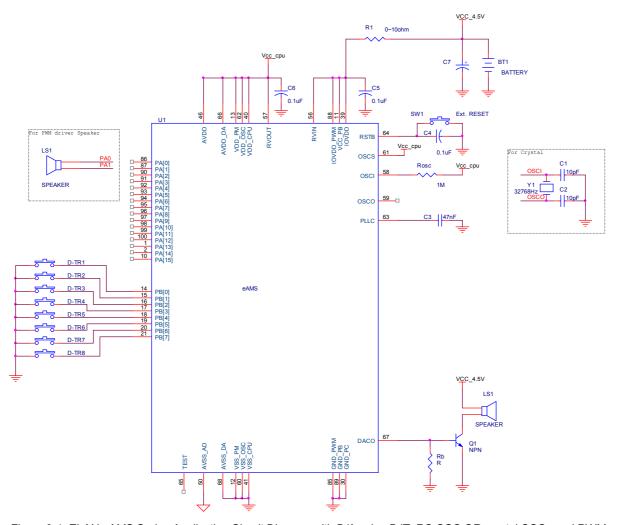


Figure 9-1 ELAN eAMS Series Application Circuit Diagram with D/A using BJT, RC OSC OR crystal OSC, and PWM for 3V/4.5V Support

NOTE

For different package type, the system characteristic issue such as power consumption due to IO pad floating must controlled by software. For example, if user don't bonding IO pad, you must set IO pad type is input with pull-up resister or output to prevent power consumption.